
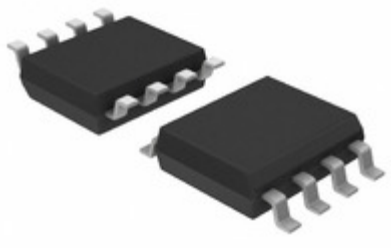



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|  | <p>Hersteller-Teilenummer: PHK12NQ10T,518</p> |
| | <p>Hersteller / Marke: NXP Semiconductors / Freescale</p> |
|  | <p>Teil der Beschreibung: MOSFET N-CH 100V 11.6A SOT96-1</p> |
| | <p>Datenblätter:  PHK12NQ10T,518.pdf</p> |
| | <p>RoHs Status: Bleifrei / RoHS-konform</p> |
| | <p>Lagerzustand: New original, Stock Available.</p> |
| | <p>Liefern von: Hong Kong</p> |
| <p>Image may be representation. See specs for product details.</p> | <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p> |

Spezifikationen

| | |
|--|---|
| Teilenummer | PHK12NQ10T,518 |
| Hersteller | NXP Semiconductors / Freescale |
| Beschreibung | MOSFET N-CH 100V 11.6A SOT96-1 |
| Kategorie | Diskrete Halbleiterprodukte > Transistoren-FETs, |
| Teilstatus | Require For Quote & Check Stock |
| VGS (th) (Max) @ Id | 4V @ 1mA |
| Technologie | MOSFET (Metal Oxide) |
| Supplier Device-Gehäuse | 8-SO |
| Serie | TrenchMOS™ |
| Rds On (Max) @ Id, Vgs | 28 mOhm @ 6A, 10V |
| Verlustleistung (max) | 8.9W (Tc) |
| Verpackung | Tape & Reel (TR) |
| Verpackung / Gehäuse | 8-SOIC (0.154", 3.90mm Width) |
| Betriebstemperatur | -55°C ~ 150°C (TJ) |
| Befestigungsart | Surface Mount |
| Eingabekapazität (Ciss) (Max) @ Vds | 1965pF @ 25V |
| Gate Charge (Qg) (Max) @ Vgs | 35nC @ 10V |
| Typ FET | N-Channel |
| FET-Merkmal | - |
| Drain-Source-Spannung (Vdss) | 100V |
| Strom - Ununterbrochener Abfluss (Id) bei 25 ° C | 11.6A (Tc) |

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RFQ PHK12NQ10T,518 E-Mail: Info@Y-IC.com

Sie können auch interessiert

| | | | |
|--|---|--|---|
| <p>sein:</p>  <p>PHK12NQ03LT. NXP PHK12NQ03LT. NXP</p> |  <p>PHK12NQ10T NXP PHK12NQ10T NXP</p> |  <p>PHK12NQ03LT,518 Nexperia USA Inc. MOSFET N-CH 30V 11.8A SOT96</p> |  <p>PHK13N03LT NXP PHK13N03LT NXP</p> |
|  <p>PHK13N03LT+518 NXP NXP SOP8</p> |  <p>PHK12NQ03LT NXP PHK12NQ03LT NXP</p> |  <p>PHK13N03LT,518 Nexperia USA Inc. MOSFET N-CH 30V 13.8A 8-SOIC</p> |  <p>PHK18N03LT NXP PHK18N03LT NXP</p> |

Verwandtes Hot-Keyword

Mehr

| | | | | |
|---|--|---|--------------------------------------|---|
| PHK12NQ10T,518 NXP Semiconductors / Freescale | PHK12NQ10T,518 Datenblatt | PHK12NQ10T,518-Datenblätter | PHK12NQ10T,518 PDF | NXP Semiconductors / Freescale PHK12NQ10T,518 |
| PHK12NQ10T,518 Electronic | PHK12NQ10T,518-Komponenten | PHK12NQ10T,518-Verteiler | PHK12NQ10T,518-Bild | PHK12NQ10T,518-Teil |
| PHK12NQ10T,518 Preis | PHK12NQ10T,518 Hersteller | PHK12NQ10T,518 Bild | PHK12NQ10T,518 Aktie | PHK12NQ10T,518 Inventar |
| PHK12NQ10T,518 Neu | PHK12NQ10T,518 Original | PHK12NQ10T,518 garantiert | PHK12NQ10T,518 RFQ | PHK12NQ10T,518 Online bestellen |

Contact us:Info@Y-IC.com

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